

# SHC615

## Wide-Bandwidth, DC RESTORATION CIRCUIT

### FEATURES

- PROPAGATION DELAY: 2.2ns
- BANDWIDTH: OTA: 750MHz  
Comparator: 280MHz
- LOW INPUT BIAS CURRENT:  $-0.3\mu\text{A}$
- SAMPLE/HOLD  
SWITCHING TRANSIENTS:  $+1/-7\text{mV}$
- SAMPLE/HOLD  
FEEDTHROUGH REJECTION: 100dB
- CHARGE INJECTION: 40fC
- HOLD COMMAND DELAY TIME: 3.8ns
- TTL/CMOS HOLD CONTROL

### DESCRIPTION

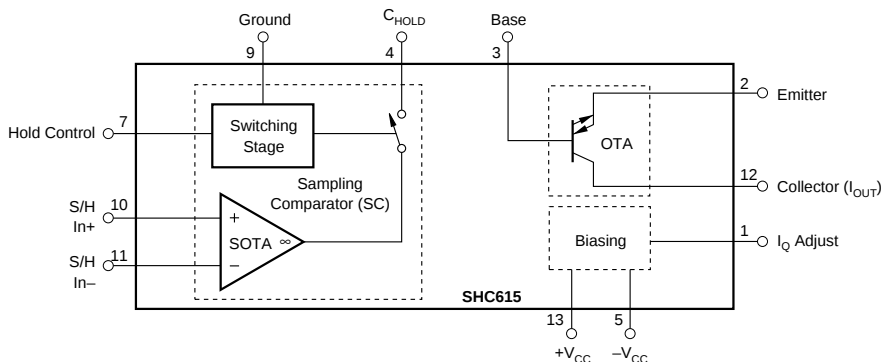
The SHC615 is a complete subsystem for very fast and precise DC restoration, offset clamping, and low frequency hum suppression of wideband amplifiers or buffers. Designed to stabilize the performance of video signals, it can also be used as a sample/hold amplifier, high-speed integrator, or peak detector for nanosecond pulses. A wideband Operational Transconductance Amplifier (OTA) with a high-impedance cascode current source output and fast sampling comparator set a new standard for high-speed applications. Both can be used as stand-alone circuits or combined to form a more complex signal processing stage. The self-biased, bipolar OTA can be viewed as an ideal voltage-controlled current source and is

### APPLICATIONS

- BROADCAST/HDTV EQUIPMENT
- TELECOMMUNICATIONS EQUIPMENT
- HIGH-SPEED DATA ACQUISITION
- CAD MONITORS/CCD IMAGE PROCESSING
- NANO SECOND PULSE INTEGRATOR/ PEAK DETECTORS
- PULSE CODE MODULATOR/ DEMODULATOR
- COMPLETE VIDEO DC LEVEL RESTORATION
- SAMPLE/HOLD AMPLIFIER

optimized for low input bias current. The sampling comparator has two identical high-impedance inputs and a current source output optimized for low output bias current and offset voltage; it can be controlled by a TTL-compatible switching stage within a few nanoseconds. The transconductance of the OTA and sampling comparator can be adjusted by an external resistor, allowing bandwidth, quiescent current, and gain tradeoffs to be optimized.

The SHC615 is available in SO-14 surface mount and 14-pin plastic DIPs, and is specified over the extended temperature range of  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ .



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Internet: <http://www.burr-brown.com/> • FAXLine: (800) 548-6133 (US/Canada Only) • Cable: BBRCORP • Telex: 066-6491 • FAX: (520) 889-1510 • Immediate Product Info: (800) 548-6132

# DC SPECIFICATIONS

At  $V_{CC} = \pm 5V$ ,  $R_{LOAD} = 100\Omega$ ,  $R_O = 300\Omega$ ,  $R_{IN} = 150\Omega$  and  $T_A = +25^\circ C$ , unless otherwise specified.

| PARAMETER                                                                                                                                 | CONDITIONS                                                                 | SHC615AP, AU |                                       |      | UNITS                          |
|-------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------|--------------|---------------------------------------|------|--------------------------------|
|                                                                                                                                           |                                                                            | MIN          | TYP                                   | MAX  |                                |
|                                                                                                                                           |                                                                            |              |                                       |      |                                |
| OFFSET VOLTAGE, V <sub>E</sub> at V <sub>B</sub> = 0<br>Initial<br>vs Temperature<br>vs Supply (tracking)                                 | V <sub>CC</sub> = ±4.5V to ±5.5V                                           | 50           | 8<br>40<br>55                         | ±40  | mV<br>μV/°C<br>dB              |
| B-INPUT BIAS CURRENT<br>Initial<br>vs Temperature                                                                                         |                                                                            |              | -0.3<br>1                             | ±0.9 | μA<br>nA/°C                    |
| C-OUTPUT BIAS CURRENT, I <sub>C</sub> at V <sub>B</sub> = 0<br>Initial                                                                    |                                                                            | -200         | -77                                   | +100 | μA                             |
| B-INPUT IMPEDANCE                                                                                                                         |                                                                            |              | 4.4                                   |      | MΩ                             |
| INPUT NOISE<br>Voltage Noise Density, B-to-E<br>Voltage Noise Density, B-to-C                                                             | f <sub>OUT</sub> = 100kHz to 100MHz<br>f <sub>OUT</sub> = 100kHz to 100MHz |              | 2.2<br>4.5                            |      | nV/√Hz<br>nV/√Hz               |
| INPUT VOLTAGE RANGE                                                                                                                       |                                                                            |              | ±3.4                                  |      | V                              |
| OUTPUT<br>Output Voltage Compliance<br>C-Current Output<br>E-Current Output<br>C-Output Impedance<br>E-Output Impedance<br>Open-Loop Gain |                                                                            | ±18<br>±18   | ±3.2<br>±20<br>±20<br>0.5<br>12<br>96 |      | V<br>mA<br>mA<br>MΩ<br>Ω<br>dB |
| TRANSCONDUCTANCE                                                                                                                          | Small Signal, <200mV                                                       |              | 70                                    |      | mA/V                           |

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## DC SPECIFICATIONS (CONT)

At  $V_{CC} = \pm 5V$ ,  $R_{LOAD} = 1k\Omega$ ,  $R_Q = 300\Omega$ , and  $T_A = +25^\circ C$ , unless otherwise specified.

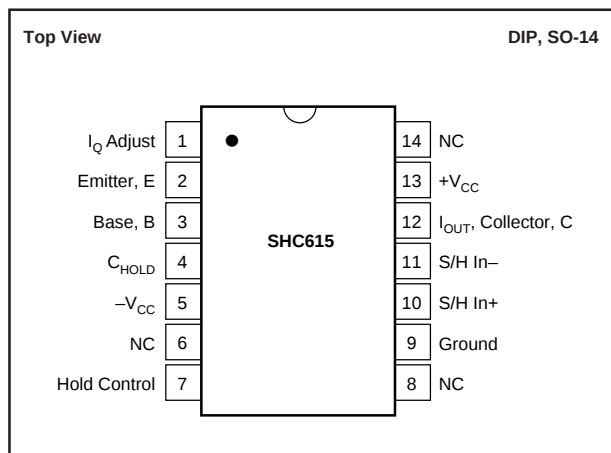
| PARAMETER                                                                                            | CONDITIONS                                           | SHC615AP, AU |                                |                              | UNITS                     |
|------------------------------------------------------------------------------------------------------|------------------------------------------------------|--------------|--------------------------------|------------------------------|---------------------------|
|                                                                                                      |                                                      | MIN          | TYP                            | MAX                          |                           |
| COMPARATOR                                                                                           |                                                      |              |                                |                              |                           |
| INPUT BIAS CURRENT<br>Initial<br>vs Temperature                                                      |                                                      |              | 1.0<br>–2.3                    | ±5                           | μA<br>nA/°C               |
| C-OUTPUT BIAS CURRENT<br>Initial<br>vs Temperature                                                   |                                                      |              | ±10<br>±13                     | ±50                          | μA<br>nA/°C               |
| INPUT IMPEDANCE<br>Input Impedance                                                                   |                                                      |              | 0.2                            |                              | MΩ                        |
| INPUT NOISE<br>Voltage Noise Density                                                                 | f <sub>OUT</sub> = 100kHz to 100MHz                  |              | 5                              |                              | nV/√Hz                    |
| INPUT VOLTAGE RANGE<br>Input Voltage Range<br>Common-Mode Input Range                                |                                                      |              | ±3.0<br>±3.2                   |                              | V<br>V                    |
| OUTPUT<br>Output Voltage Compliance<br>C-Current Output<br>C-Output Impedance<br>Open-Loop Gain      |                                                      | ±2.5         | ±3.5<br>±3.2<br>620    2<br>83 |                              | V<br>mA<br>kΩ    pF<br>dB |
| TRANSCONDUCTANCE<br>Transconductance                                                                 |                                                      |              | 22                             |                              | mA/V                      |
| HOLD CONTROL<br>Logic 1 Voltage<br>Logic 0 Voltage<br>Logic 1 Current<br>Logic 0 Current             | V Hold Control = 5.0V<br>V Hold Control = 0.8V       | +2<br>0      | 1<br>0.05                      | +V <sub>CC</sub> +0.6<br>0.8 | V<br>V<br>μA<br>μA        |
| TRANSFER CHARACTERISTICS<br>Charge Injection<br>Feedthrough Rejection                                | Track-To-Hold<br>Hold Mode                           |              | 40<br>–100                     |                              | fC<br>dB                  |
| COMPLETE SHC615                                                                                      |                                                      |              |                                |                              |                           |
| POWER SUPPLY<br>Rated Voltage<br>Derated Performance<br>Quiescent Current<br>Quiescent Current Range | R <sub>O</sub> = 300Ω<br>Programmable (Useful Range) | ±4.5<br>±12  | ±5<br>±15<br>±3 to ±36         | ±5.5<br>±18                  | V<br>V<br>mA<br>mA        |
| TEMPERATURE RANGE<br>Operating<br>Storage                                                            |                                                      | –40<br>–40   |                                | +85<br>+125                  | °C<br>°C                  |

# AC SPECIFICATIONS

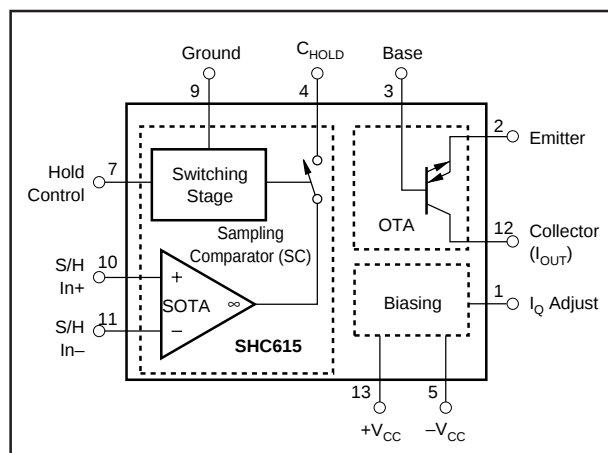
At  $V_{CC} = \pm 5V$ ,  $R_{LOAD} = 100\Omega$ ,  $R_{SOURCE} = 50\Omega$ ,  $R_Q = 300\Omega$ , and  $T_A = +25^\circ C$ , unless otherwise specified.

| PARAMETER                                                                                 | CONDITIONS                                                                                 | SHC615AP, AU |      |     | UNITS |
|-------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------|--------------|------|-----|-------|
|                                                                                           |                                                                                            | MIN          | TYP  | MAX |       |
| FREQUENCY DOMAIN                                                                          |                                                                                            |              |      |     |       |
| OTA                                                                                       |                                                                                            |              |      |     |       |
| LARGE-SIGNAL BANDWIDTH<br>(−3dB), (B-to-E)                                                | V <sub>OUT</sub> = 5.0Vp-p                                                                 |              | 430  |     | MHz   |
|                                                                                           | V <sub>OUT</sub> = 2.8Vp-p                                                                 |              | 540  |     | MHz   |
|                                                                                           | V <sub>OUT</sub> = 1.4Vp-p                                                                 |              | 620  |     | MHz   |
| SMALL-SIGNAL BANDWIDTH B-TO-E                                                             | V <sub>OUT</sub> = 0.2Vp-p                                                                 |              | 520  |     | MHz   |
| DIFFERENTIAL GAIN (B-TO-E)                                                                | f = 4.43MHz, V <sub>OUT</sub> = 0.7Vp-p,<br>R <sub>L</sub> = 150Ω<br>R <sub>L</sub> = 500Ω |              | 1.8  |     | %     |
|                                                                                           |                                                                                            |              | 0.1  |     | %     |
| DIFFERENTIAL PHASE<br>(B-to-E)                                                            | f = 4.43MHz, V <sub>OUT</sub> = 0.7Vp-p,<br>R <sub>L</sub> = 150Ω<br>R <sub>L</sub> = 500Ω |              | 0.07 |     | °     |
|                                                                                           |                                                                                            |              | 0.01 |     | °     |
| HARMONIC DISTORTION (B-TO-E)<br>Second Harmonic<br>Third Harmonic                         | f = 30MHz, V <sub>OUT</sub> = 1.4Vp-p                                                      |              | −50  |     | dBc   |
|                                                                                           |                                                                                            |              | −46  |     | dBc   |
| LARGE SIGNAL BANDWIDTH<br>(−3dB), (B-to-C)                                                | V <sub>OUT</sub> = 5.0Vp-p                                                                 |              | 250  |     | MHz   |
|                                                                                           | V <sub>OUT</sub> = 2.8Vp-p                                                                 |              | 580  |     | MHz   |
|                                                                                           | V <sub>OUT</sub> = 1.4Vp-p                                                                 |              | 750  |     | MHz   |
| SMALL SIGNAL BANDWIDTH<br>B-to-C                                                          | V <sub>OUT</sub> = 0.2Vp-p                                                                 |              | 680  |     | MHz   |
| COMPARATOR                                                                                | Sample Mode                                                                                |              |      |     |       |
| BANDWIDTH<br>(−3dB)                                                                       | I <sub>OUT</sub> = 4mA p-p                                                                 |              | 240  |     | MHz   |
|                                                                                           | I <sub>OUT</sub> = 2mA p-p                                                                 |              | 270  |     | MHz   |
|                                                                                           | I <sub>OUT</sub> = 1mA p-p                                                                 |              | 280  |     | MHz   |
| TIME DOMAIN                                                                               |                                                                                            |              |      |     |       |
| OTA                                                                                       |                                                                                            |              |      |     |       |
| RISE TIME                                                                                 | 2Vp-p Step, 10% to 90%<br>B-to-E<br>B-to-C                                                 |              | 1.1  |     | ns    |
|                                                                                           |                                                                                            |              | 1.2  |     | ns    |
| SLEW RATE                                                                                 | 2Vp-p, B-to-E                                                                              |              | 1800 |     | V/μs  |
|                                                                                           | B-to-C                                                                                     |              | 1700 |     | V/μs  |
|                                                                                           | 5Vp-p, B-to-E                                                                              |              | 3300 |     | V/μs  |
|                                                                                           | B-to-C                                                                                     |              | 3000 |     | V/μs  |
| COMPARATOR                                                                                |                                                                                            |              |      |     |       |
| RISE TIME<br>(Sample Mode)                                                                | 10% to 90%, R <sub>L</sub> = 50Ω, I <sub>OUT</sub> = ±2mA<br>C <sub>LOAD</sub> = 1pF       |              | 2.5  |     | ns    |
| SLEW RATE<br>(Sample Mode)                                                                | 10% to 90%, R <sub>L</sub> = 50Ω, I <sub>OUT</sub> = ±2mA<br>C <sub>LOAD</sub> = 1pF       |              | 0.95 |     | mA/ns |
| DYNAMIC CHARACTERISTICS<br>Propagation Delay Time<br>Propagation Delay Time<br>Delay Time | t <sub>PDH</sub> , V <sub>OD</sub> = 200mV                                                 |              | 2.2  |     | ns    |
|                                                                                           | t <sub>PDL</sub> , V <sub>OD</sub> = 200mV                                                 |              | 2.15 |     | ns    |
|                                                                                           | Sample-to-Hold                                                                             |              | 3.8  |     | ns    |
|                                                                                           | Hold-to-Sample                                                                             |              | 3.0  |     | ns    |

## PIN CONFIGURATION



## BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

|                                       |                                   |
|---------------------------------------|-----------------------------------|
| Power Supply Voltage ( $\pm V_{CC}$ ) | $\pm 6V$                          |
| Input Voltage <sup>(1)</sup>          | $\pm V_{CC} \pm 0.7V$             |
| Operating Temperature                 | $-40^{\circ}C$ to $+85^{\circ}C$  |
| Storage Temperature                   | $-40^{\circ}C$ to $+125^{\circ}C$ |
| Junction Temperature                  | $+150^{\circ}C$                   |
| Lead Temperature (soldering, 10s)     | $+300^{\circ}C$                   |
| Hold Control                          | $-0.5V$ to $+V_{CC} + 0.7V$       |

NOTE: (1) Inputs are internally diode-clamped to  $\pm V_{CC}$ .

## PACKAGE/ORDERING INFORMATION

| PRODUCT  | PACKAGE                  | PACKAGE DRAWING NUMBER <sup>(1)</sup> | TEMPERATURE RANGE                |
|----------|--------------------------|---------------------------------------|----------------------------------|
| SHC615AP | Plastic 14-Pin DIP       | 010                                   | $-40^{\circ}C$ to $+85^{\circ}C$ |
| SHC615AU | SO 14-Lead Surface-Mount | 235                                   | $-40^{\circ}C$ to $+85^{\circ}C$ |

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.



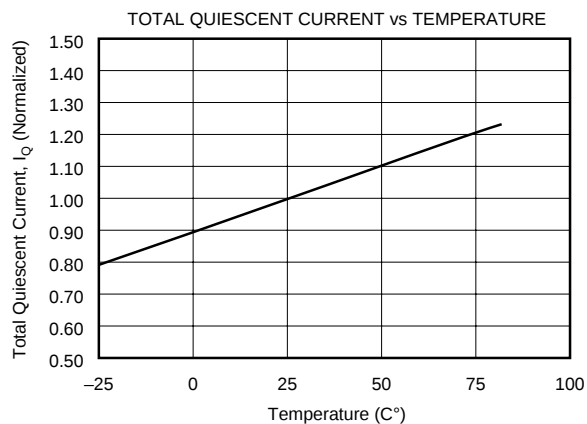
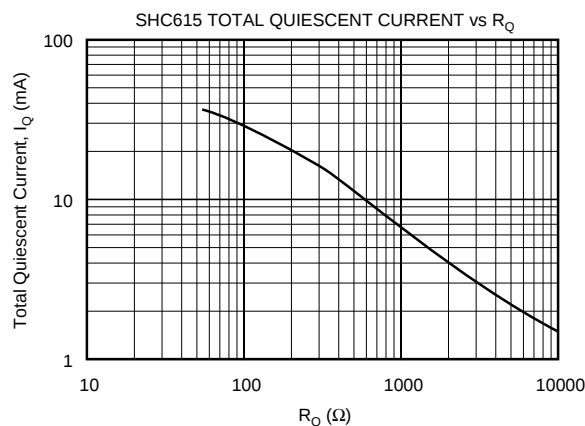
## ELECTROSTATIC DISCHARGE SENSITIVITY

Any integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

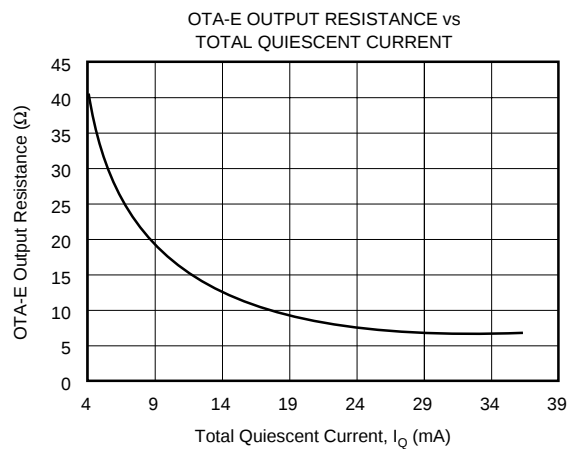
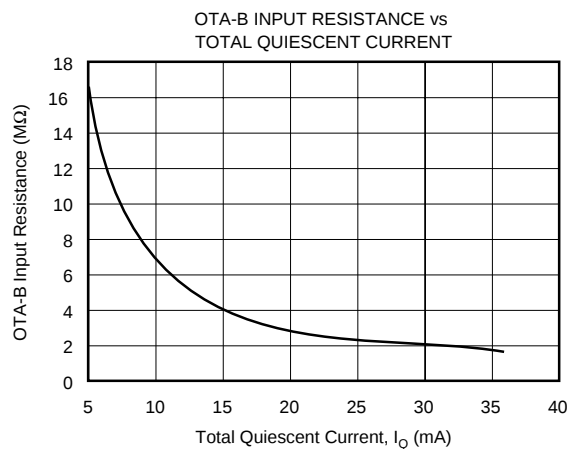
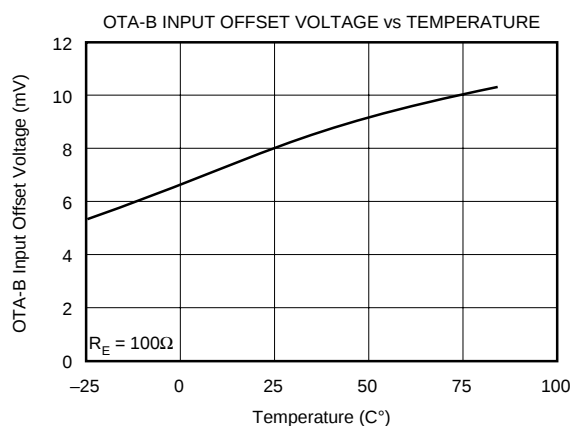
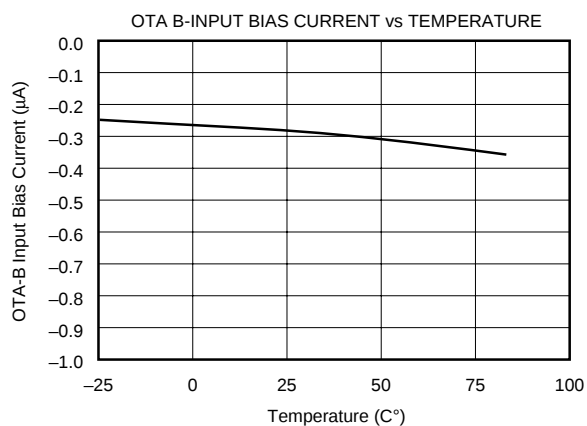
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet published specifications.

# TYPICAL PERFORMANCE CURVES

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.

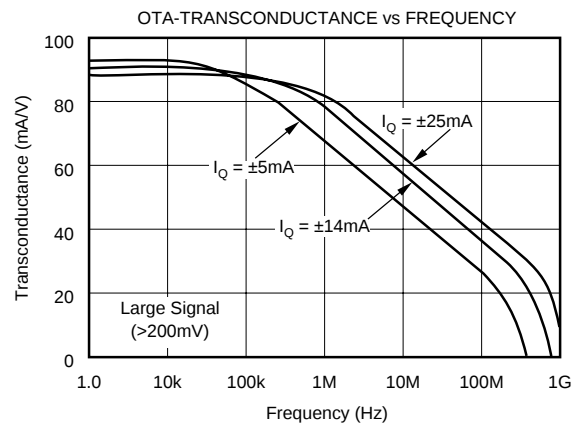
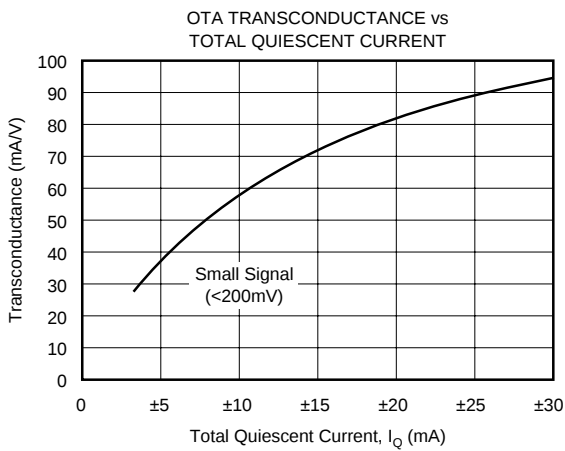
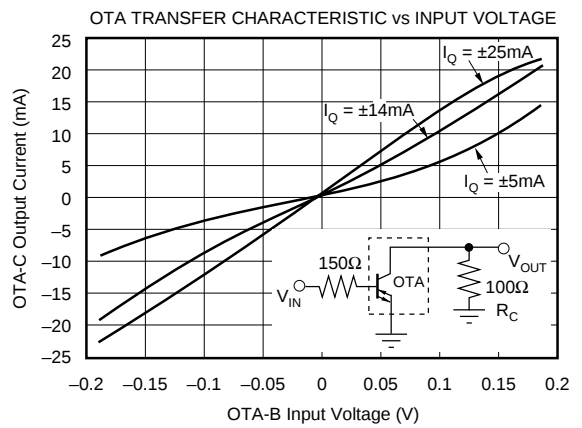
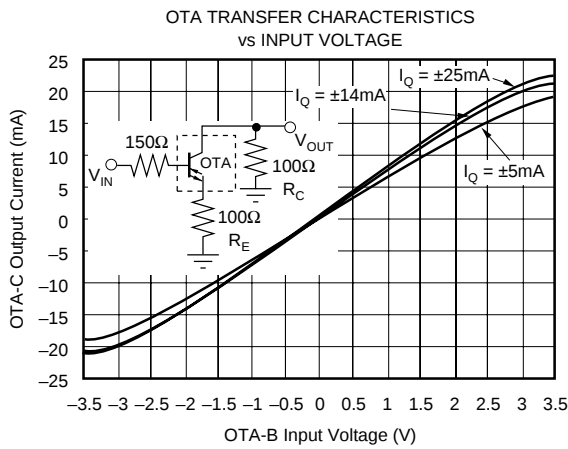
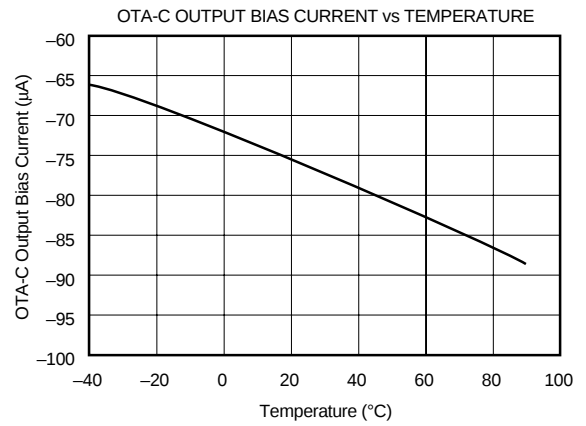
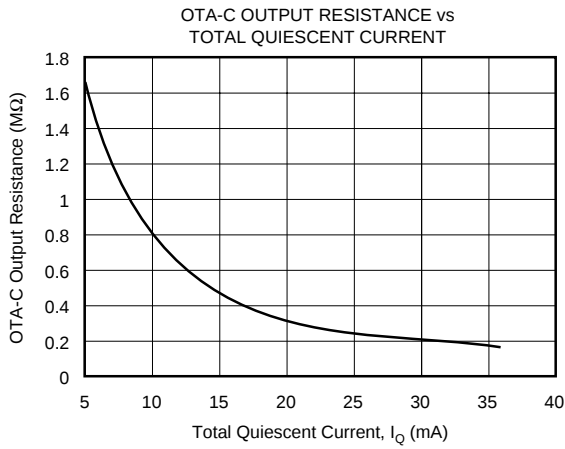


## OPERATIONAL TRANSCONDUCTANCE AMPLIFIER



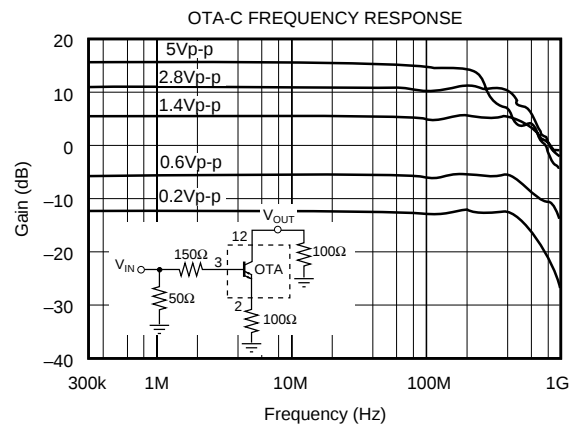
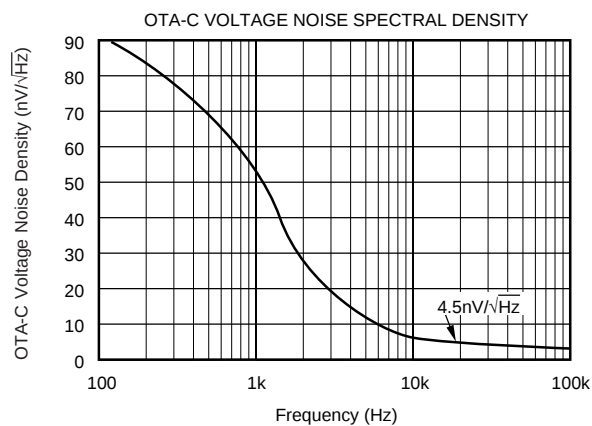
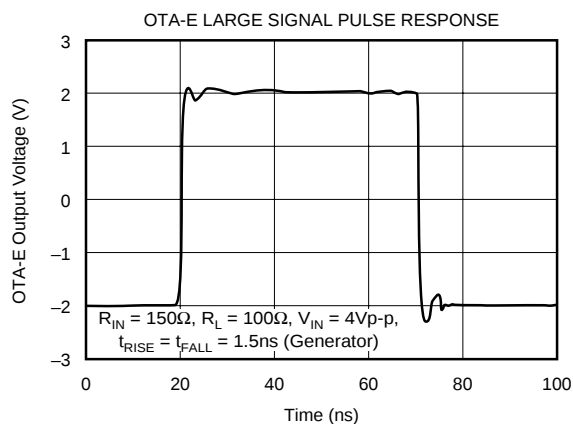
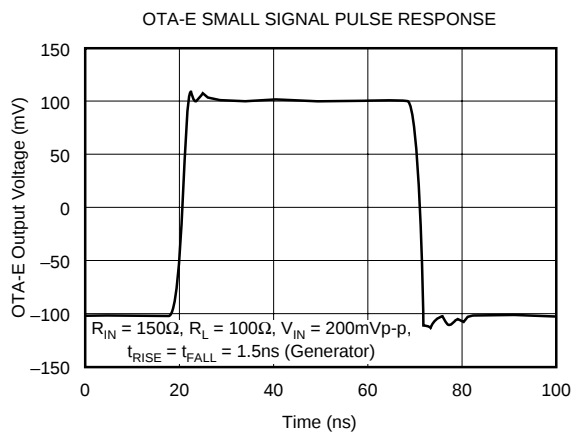
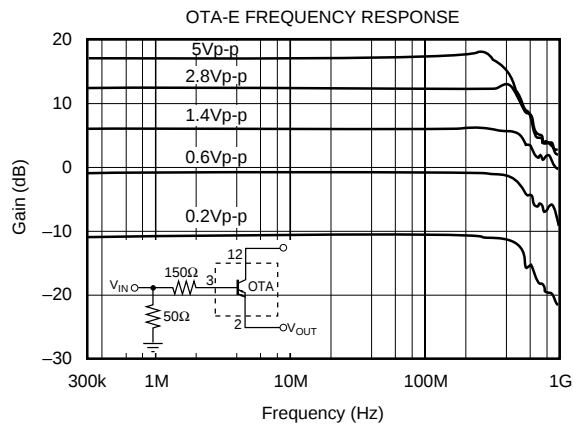
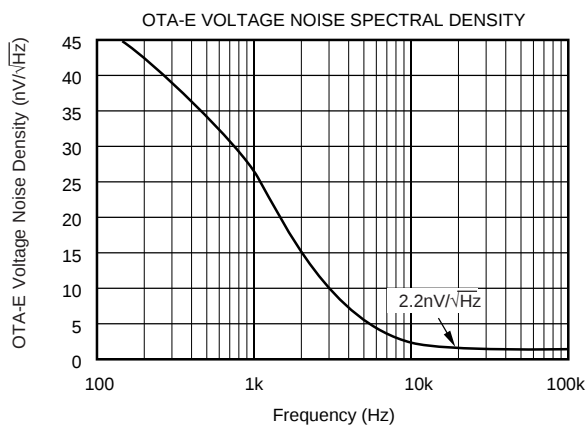
# TYPICAL PERFORMANCE CURVES (CONT)

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.



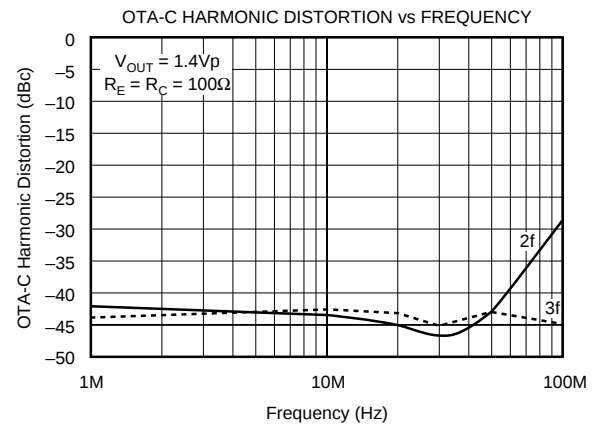
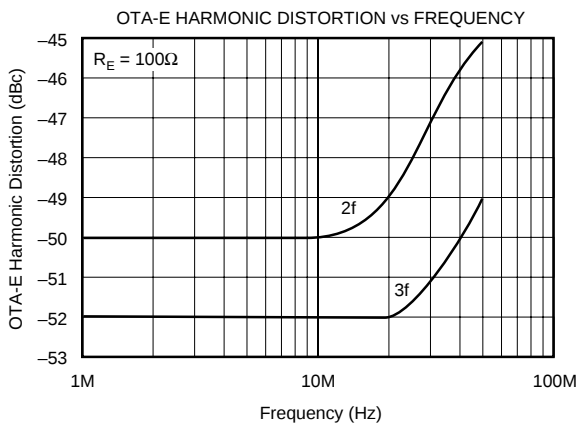
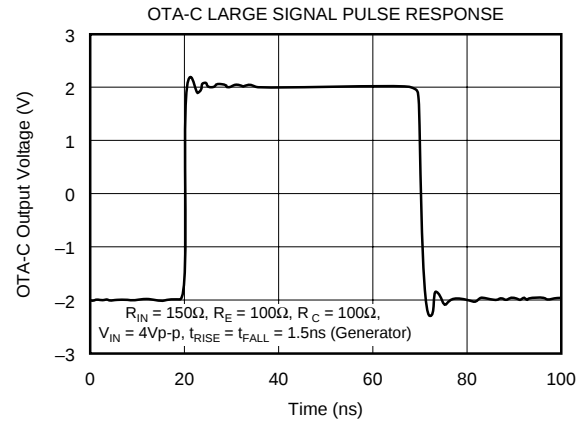
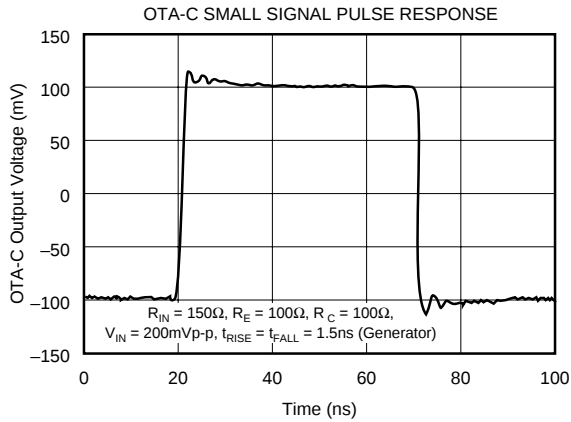
# TYPICAL PERFORMANCE CURVES (CONT)

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.

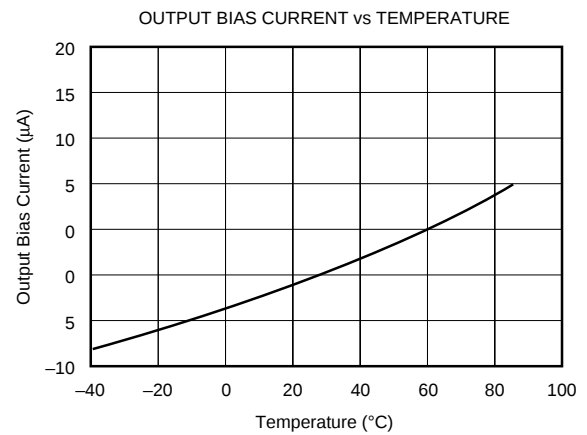
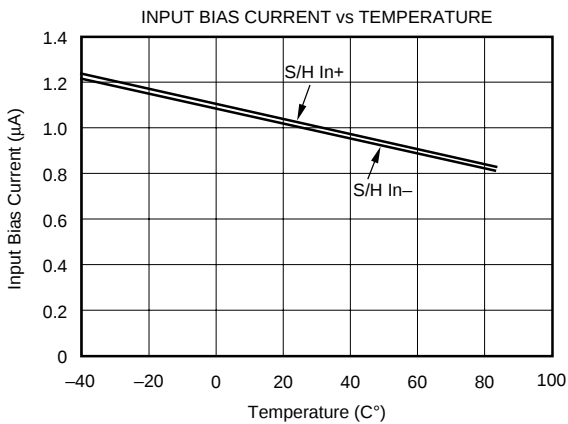


## TYPICAL PERFORMANCE CURVES (CONT)

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.

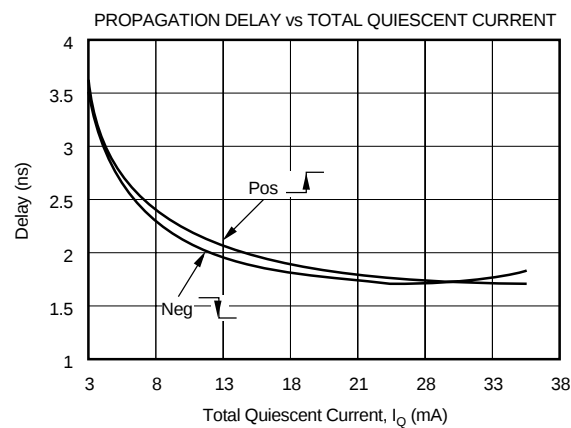
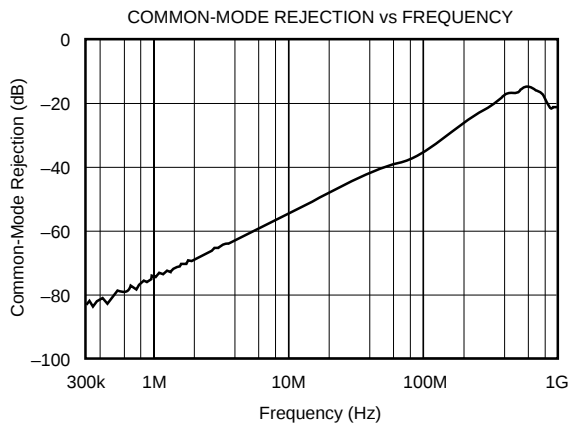
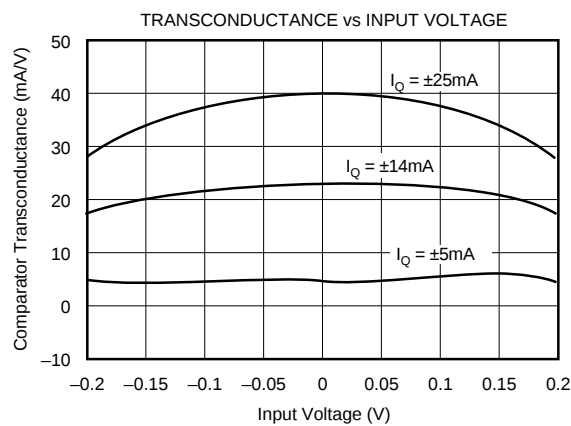
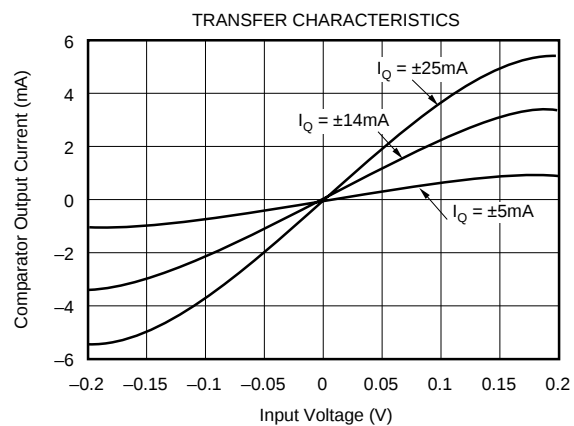
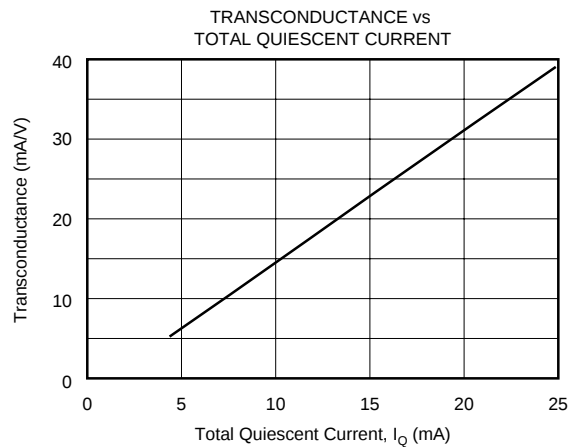
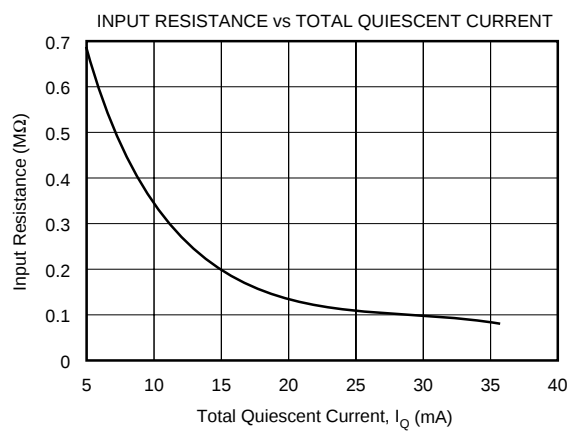


## SAMPLING COMPARATOR



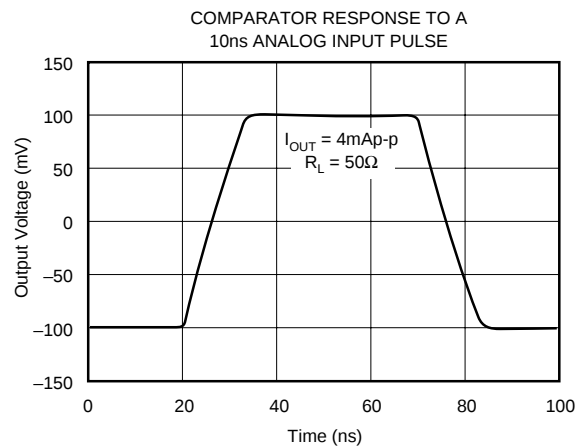
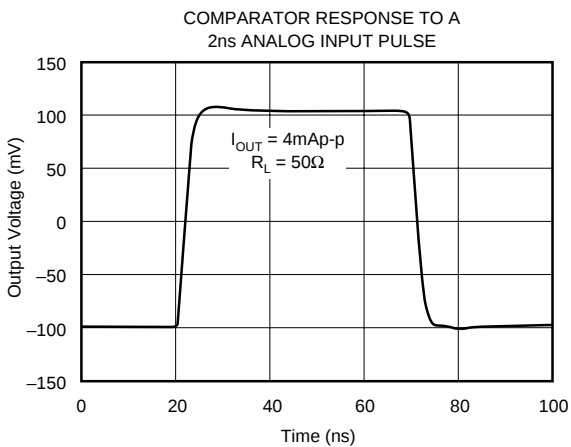
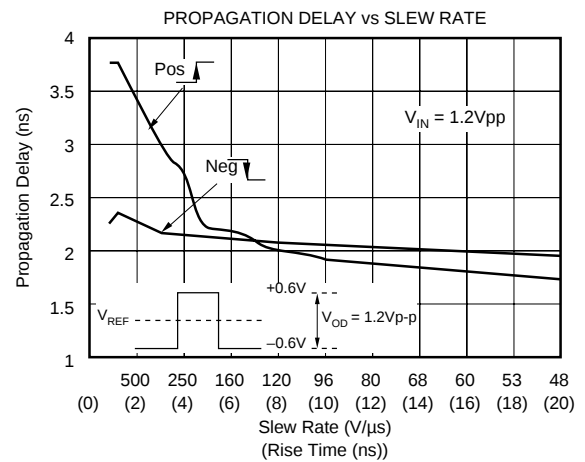
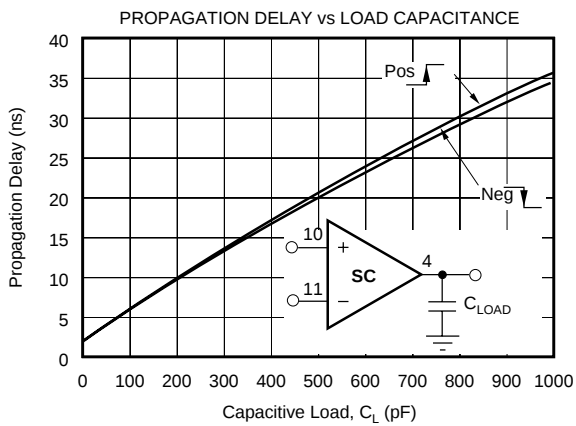
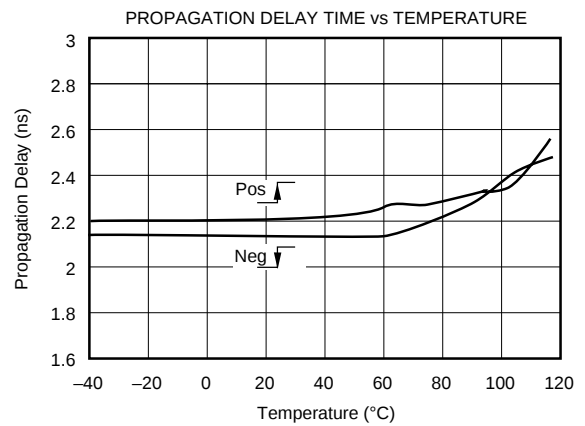
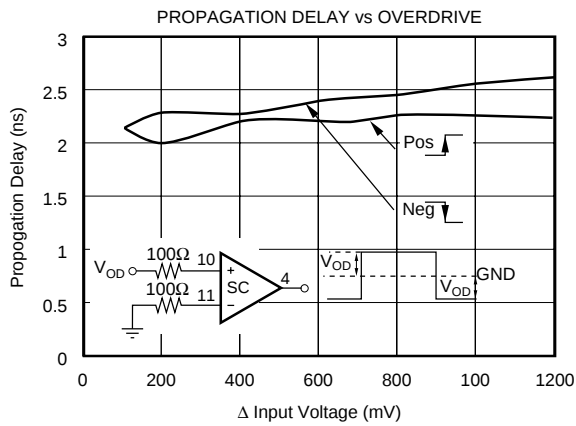
# TYPICAL PERFORMANCE CURVES (CONT)

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.



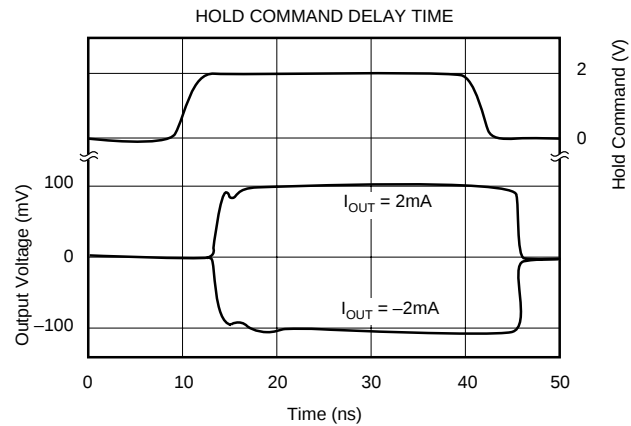
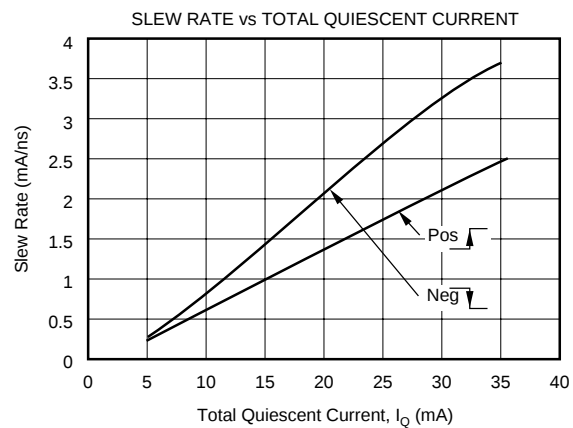
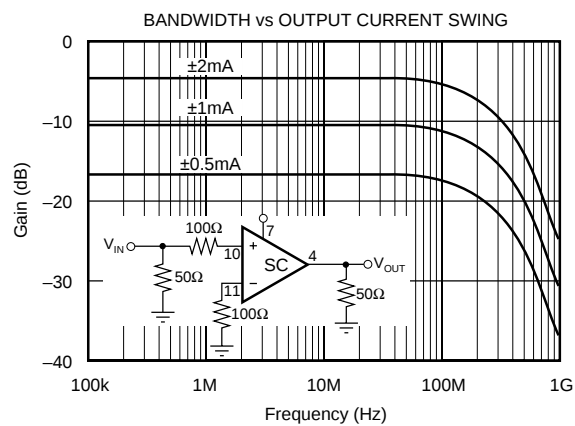
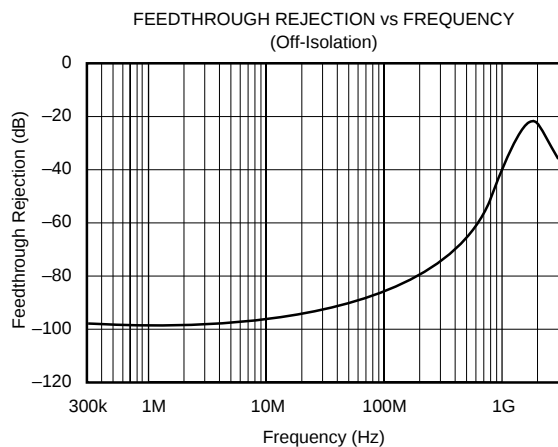
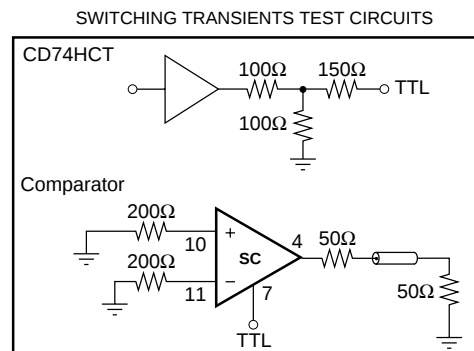
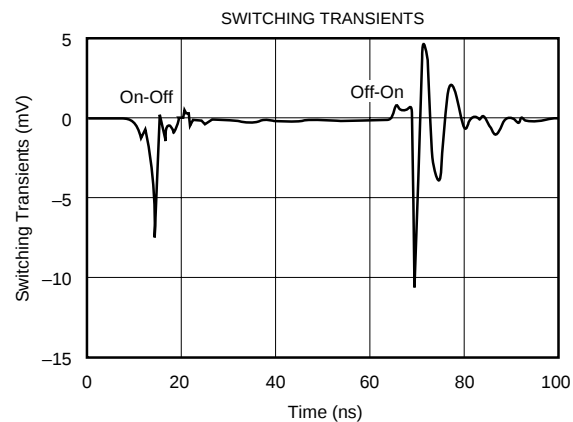
## TYPICAL PERFORMANCE CURVES (CONT)

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.



# TYPICAL PERFORMANCE CURVES (CONT)

At  $R_Q = 300\Omega$ ,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 5\text{V}$ , unless otherwise noted.



## DISCUSSION OF PERFORMANCE

The SHC615, which contains a wideband Operational Transconductance Amplifier and a fast sampling comparator, represents a complete subsystem for very fast and precise DC restoration, offset clamping and correction to GND or to an adjustable reference voltage, and low frequency hum suppression of wideband operational or buffer amplifiers.

Although the IC was designed to improve or stabilize the performance of complex, wideband video signals, it can also be used as a sample and hold amplifier, high-speed integrator, peak detector for nanosecond pulses, or demodulator or modulator for pulse code transmission systems. A wideband Operational Transconductance Amplifier (OTA) with a high-impedance cascode current source output and a fast and precise sampling comparator set a new standard for high-speed sampling applications.

Both can be used as stand-alone circuits or combined to create more complex signal processing stages like sample and hold amplifiers. The SHC615 simplifies the design of input amplifiers with high hum suppression, clamping or DC-restoration stages in professional broadcast equipment, high-resolution CAD monitors and information terminals, signal processing stages for the energy and peak value of small and fast nanoseconds pulses, and eases the design of high-speed data acquisition systems behind a CCD sensor or in front of an analog-to-digital converter.

An external resistor,  $R_Q$ , allows the user to set the quiescent current.  $R_Q$  is connected from Pin 1 ( $I_Q$  adjust) to  $-V_{CC}$ . It determines the operating currents of both the OTA and comparator sections and controls the bandwidth and AC behavior as well as the transconductance of both sections. Besides the quiescent current setting feature, the Proportional-to-Absolute-Temperature (PTAT) supply increases the quiescent current vs temperature and keeps it constant over a wide range of input voltages. This variation holds the transconductance  $g_m$  of the OTA and comparator relatively constant vs temperature. The circuit parameters listed in the specification table are measured with  $R_Q$  set to  $300\Omega$ , giving a nominal quiescent current at  $\pm 15\text{mA}$ . The circuit can be totally switched-off with a current flowing into Pin 1.

## OPERATIONAL TRANSCONDUCTANCE AMPLIFIER (OTA)

### SECTION AND OVERVIEW

The symbol for the OTA section is similar to that of a bipolar transistor, and the self-biased OTA can be viewed as a quasi-ideal transistor or as a voltage-controlled current source. Application circuits for the OTA look and operate much like transistor circuits—the bipolar transistor, also, is a voltage-controlled current source. Like a transistor, it has three terminals: a high-impedance input (base) optimized for a low input bias current of  $0.3\mu\text{A}$ , a low-impedance input/

output (emitter), and the high-impedance current output (collector).

The OTA consists of a complementary buffer amplifier and a subsequent complementary current mirror. The buffer amplifier features a Darlington output stage and the current mirror has a cascoded output. The addition of this cascode circuitry increases the current source output resistance to  $1\text{M}\Omega$  and the open-loop gain to typically 96dB. Both features improve the OTAs linearity and drive capabilities. Any bipolar input voltage at the high impedance base has the same polarity and signal level at the low impedance buffer or emitter output. For the open-loop diagrams the emitter is connected to GND and then the collector current is determined by the product voltage between base and emitter times the transconductance. In application circuits (Figure 2b.), a resistor  $R_E$  between emitter and GND is used to set the OTA transfer characteristics. The following formulas describe the most important relationships.  $r_E$  is the output impedance of the buffer amplifier (emitter) or the reciprocal of the OTA transconductance. Above  $\pm 5\text{mA}$ , collector current,  $I_C$ , will be slightly less than indicated by the formula.

$$I_C = \frac{V_{IN}}{r_E + R_E} \quad R_E = \frac{V_{IN}}{I_C} - r_E$$

The  $R_E$  resistor may be bypassed by a relatively large capacitor to maintain high AC gain. The parallel combination of  $R_E$  and this large capacitor form a high pass filter enhancing the high frequency gain. Other cases may require a RC compensation network parallel to  $R_E$  to optimize the high-frequency response. The full power bandwidth measured at the emitter achieves 620MHz. The frequency response of the collector is directly related to the resistor's value between collector and GND; it decreases with increasing resistor values, because it forms a low-pass network with the OTA C-output capacitance.

Figure 1 shows a simplified block and circuit diagram of the SHC615 OTA. Both the emitter and the collector outputs offer a drive capability of  $\pm 20\text{mA}$  for driving low impedance lines or inputs. Connecting the collector to the emitter in a direct-feedback buffer configuration increases the drive capability to  $\pm 40\text{mA}$ . The emitter output is not current-limited or protected. Momentary shorts to GND should be avoided, but are unlikely to cause permanent damage.

While the OTA's function and labeling looks similar to that of transistors, it offers essential distinctive differences and improvements: 1) The collector current flows out of the C terminal for a positive B-to-E input voltage and into it for negative voltages; 2) A common emitter amplifier operates in non-inverting mode while the common base operates in inverting mode; 3) The OTA is far more linear than a bipolar transistor; 4) The transconductance can be adjusted with an external resistor; 5) Due to the PTAT biasing characteristic the quiescent current increases as shown in the typical performance curve vs temperature and keeps the AC performance constant; 6) The OTA is self-biased and bipolar; and, 7) The output current is zero for zero differential input voltages. AC inputs centered at zero produce an output current centered at zero.

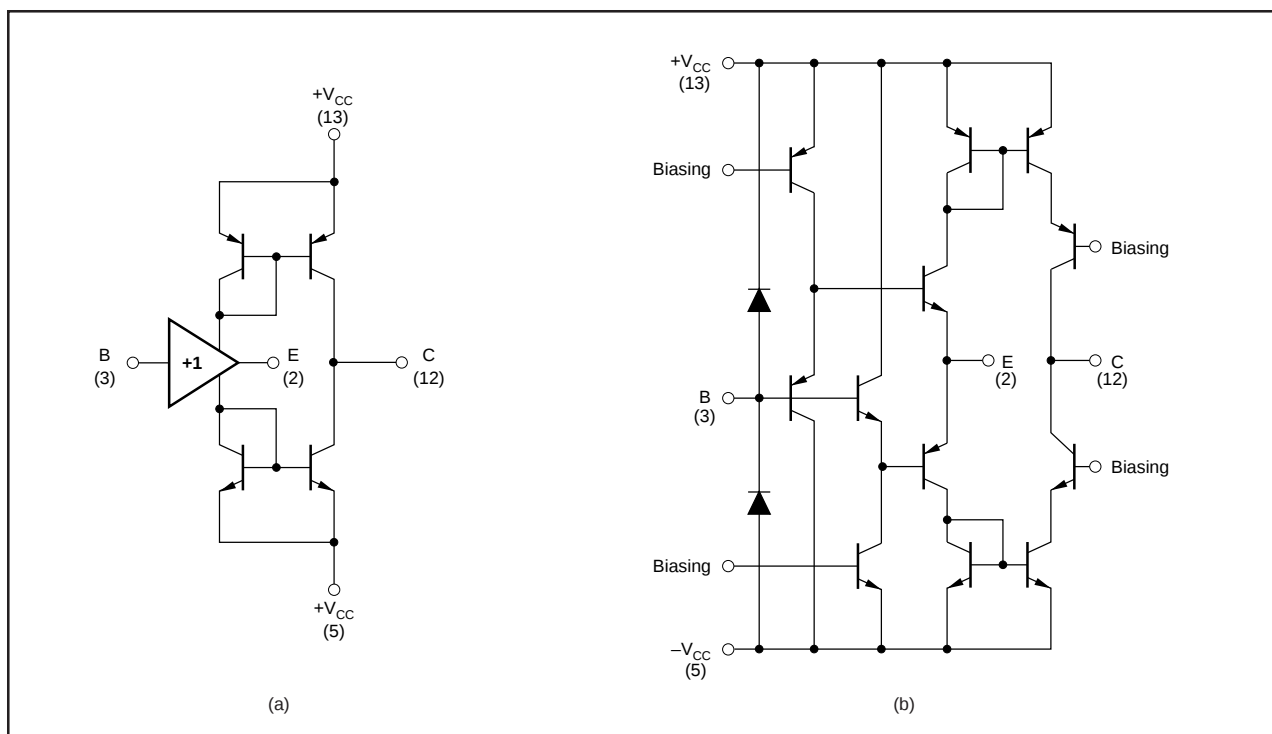


FIGURE 1. a) Simplified Block; and, b) Circuit Diagram of the OTA Section.

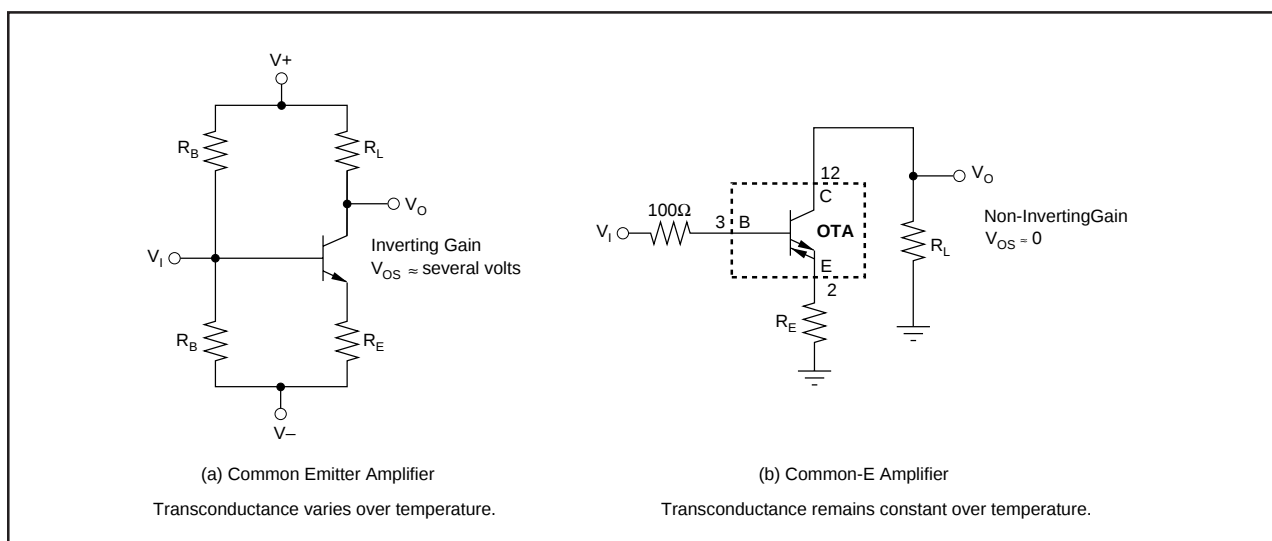


FIGURE 2. a) Common Emitter Amplifier Using a Discrete Transistor; b) Common-E Amplifier Using the OTA Portion of the SHC615.

## BASIC APPLICATIONS CIRCUITS

Most application circuits for the OTA section consist of a few basic types which are best understood by analogy to discrete transistor circuits. Just as the transistor has three basic operating modes—common emitter, common base, and common collector—the OTA has three equivalent operating modes common-E, common-B, and common-C (See Figures 2, 3 and 4). Figure 2 shows the OTA connected as

a Common-E amplifier which is equivalent to a common emitter transistor amplifier. Input and output can be ground referenced without any biasing. Due to the sense of the output current, the amplifier is non-inverting.

Figure 4 shows the common-B amplifier. This configuration produces an inverting gain, and the input is low-impedance. When a high impedance input is needed, it can be created by inserting a buffer amplifier like BUF600 in series.

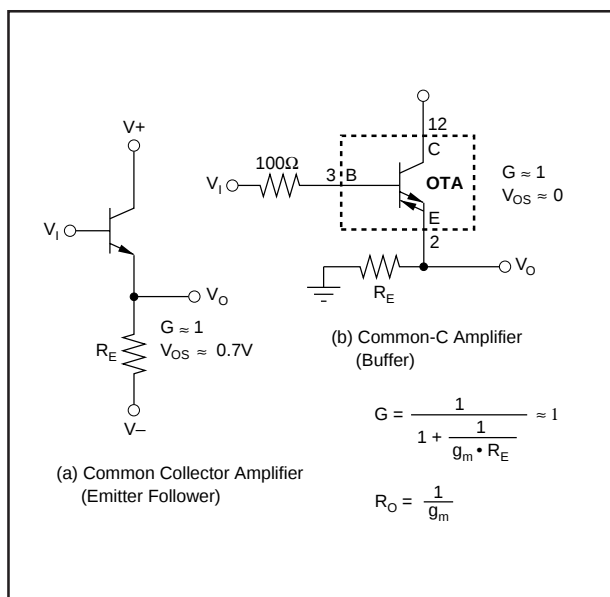


FIGURE 3. a) Common Collector Amplifier Using a Discrete Transistor; b) Common-C Amplifier Using the OTA Portion of the SHC615.

### SAMPLING COMPARATOR

The SHC615 sampling comparator features a very short 2.2ns propagation delay and utilizes a new switching circuit architecture to achieve excellent speed and precision.

It provides high impedance inverting and non-inverting inputs, a high-impedance current source output and a TTL-CMOS-compatible Hold Control Input.

The sampling comparator consists of an operational transconductance amplifier (OTA), a buffer amplifier, and a subsequent switching circuit. The OTA and buffer amplifier are directly tied together at the buffer outputs to provide the two identical high-impedance inputs and high open-loop transconductance. Even a small differential input voltage multiplied with the high transconductance results in an output current—positive or negative—depending upon the input polarity. This is similar to the low or high status of a conventional comparator. The current source output features high output impedance, output bias compensation, and is optimized for charging a capacitor in DC restoration, nanosecond integrators, peak detectors and S/H circuits. The typical comparator output current is  $\pm 3.2mA$  and the output bias current is minimized to typically  $\pm 10\mu A$  in the sampling mode.

This innovative circuit achieves the slew rate representatives of an open-loop design. In addition, the acquisition slew current for a hold or storage capacitor is higher than standard diode bridge and switch configurations, removing a main contributor to the limits of maximum sampling rate and input frequency.

The switching circuits in the SHC615 use current steering (versus voltage switching) to provide improved isolation between the switch and analog sections. This results in low aperture time sensitivity to the analog input signal, reduced power supply and analog switching noise. Sample-to-hold peak switching is 40fC.

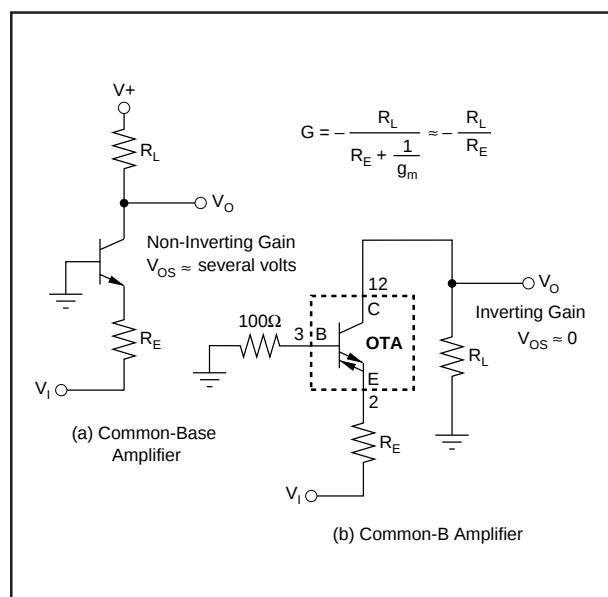


FIGURE 4. a) Common Base Amplifier Using a Discrete Transistor; b) Common-B Amplifier Using the OTA Portion of the SHC615.

The additional offset voltage or switching transient induced on a capacitor at the current source output by the switching charge can be determined by the following formula:

$$\text{Offset}(V) = \frac{\text{Charge}(pC)}{C_H \text{ Total}(pF)}$$

The switching stage input is insensitive to the low slew rate performance of the hold control command and compatible with TTL/CMOS logic levels. With a TTL logic high, the comparator is active, comparing the two input voltages and varying the output current accordingly. With a TTL logic low, the comparator output is switched off.

## APPLICATION INFORMATION

The SHC615 operates from  $\pm 5V$  power supplies ( $\pm 6V$  maximum). Do not attempt to operate with larger power supply voltages or permanent damage may occur.

Inputs of the SHC615 are protected with internal diode clamps as shown in Figure 1. These protection diodes can safely conduct 10mA continuously (30mA peak). If input voltages can exceed the power supply voltages by 0.7V, the input signal current must be limited.

### BASIC CONNECTIONS

Figure 6 shows the basic connections required for operation. These connections are not shown in subsequent circuit diagrams. Power supply bypass capacitors should be located as close as possible to the device pins. Solid tantalum capacitors are generally best. See "Circuit Layout" at the end of the applications discussion for further suggestions on layout.

If the high speed TTL-hold command signal goes negative due to reflections for AC-coupling, the hold control input must be protected by an external reverse bias diode to ground as shown in Figure 6.

## CIRCUIT LAYOUT

The high-frequency performance of the SHC615 can be greatly affected by the physical layout of the printed circuit board. The following tips are offered as suggestions, not as absolute requirements. Oscillations, ringing, poor bandwidth, poor settling, and peaking are all typical problems that

plague high-speed components when they are used incorrectly.

- Bypass power supplies very close to the device pins. Use tantalum chip capacitors (approximately 2.2 $\mu$ F); parallel 470pF and/or 10nF ceramic chip capacitors may be added if desired. Surface mount types are recommended because of their low lead inductance. Supply bypassing is extremely critical at high frequencies and when driving high current loads.
- PC board traces for power lines should be wide to reduce impedance.

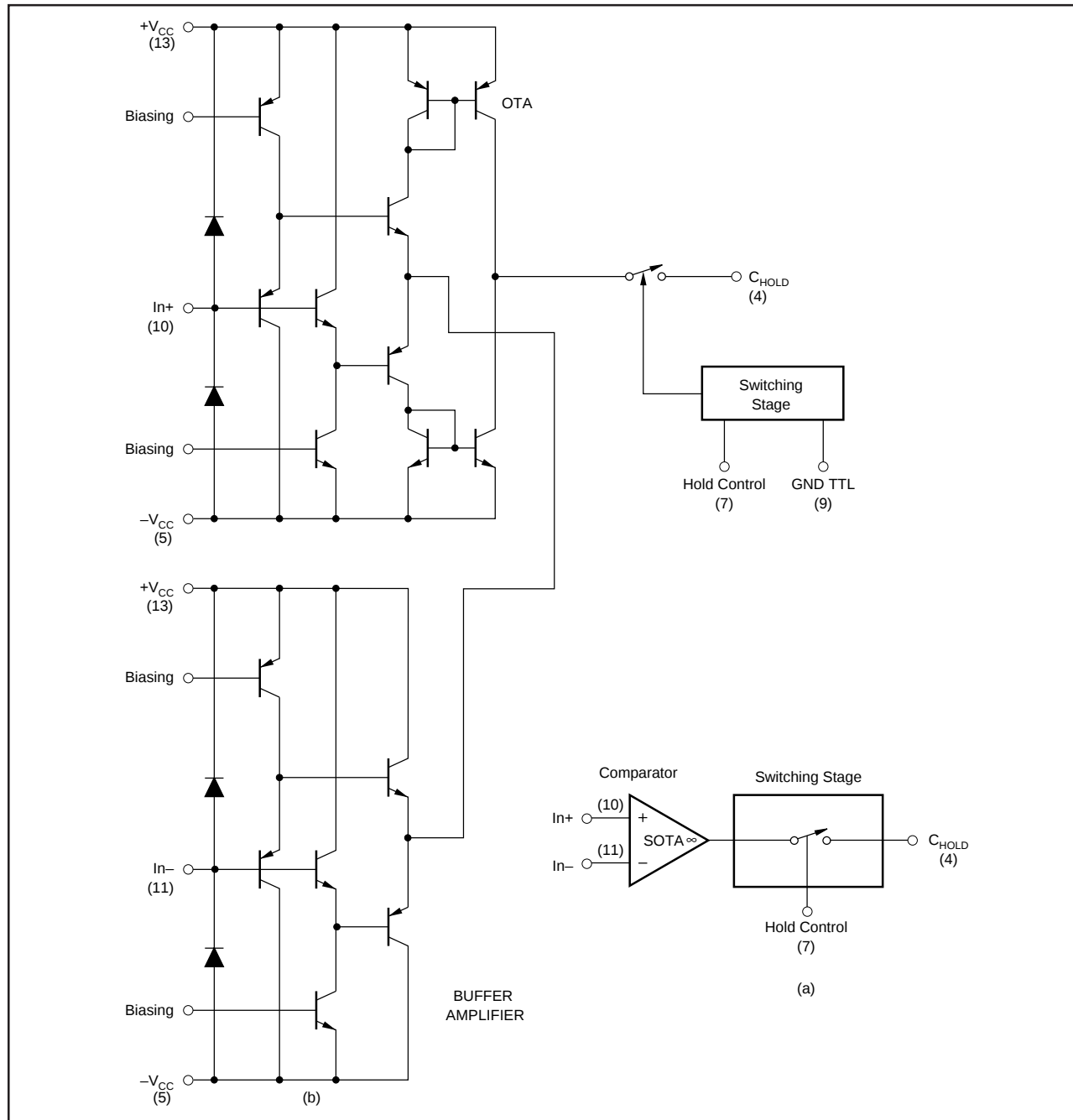


FIGURE 5. a) Simplified Block Diagram; and, b) Circuit Diagram of the Sampling Comparator which Includes the Sampling Operational Transconductance Amplifier (SOTA) and the Switching Stage.

- Make short, low-inductance traces. The entire physical circuit should be as small as possible.
- Use a low-impedance ground plane on the component side to ensure that a low-impedance ground is available throughout the layout.
- Do not extend the ground plane under high-impedance nodes sensitive to stray capacitances such as the amplifier's input terminals.
- Sockets are not recommended since they add significant inductance and parasitic capacitance. If sockets are required, use zero-profile sockets.
- Use low-inductance, surface-mount components. Surface-mount components offer the best AC performance.
- A resistor of 100 to 250 $\Omega$  in series with the high-impedance inputs is recommended to reduce peaking.
- Plug-in prototype boards and wire-wrap boards will not function well. A clean layout using RF techniques is essential—there are no shortcuts.
- Terminate transmission line loads. Unterminated lines, such as box cables, can appear to the amplifier to be a capacitive or inductive load. By terminating a transmission line with its characteristic impedance, the amplifier's load then appears purely resistive.
- Protect the hold control input with an external diode if necessary.

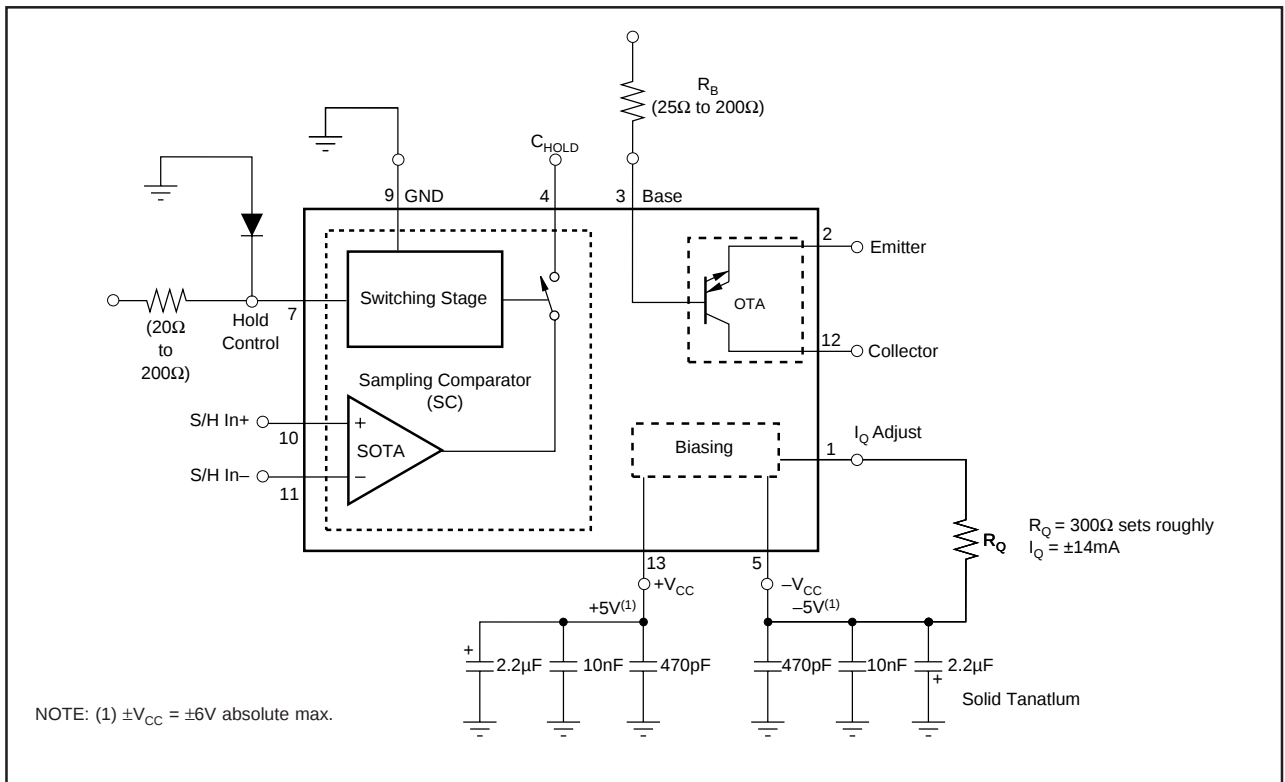


FIGURE 6. Basic Connections

## TYPICAL APPLICATIONS

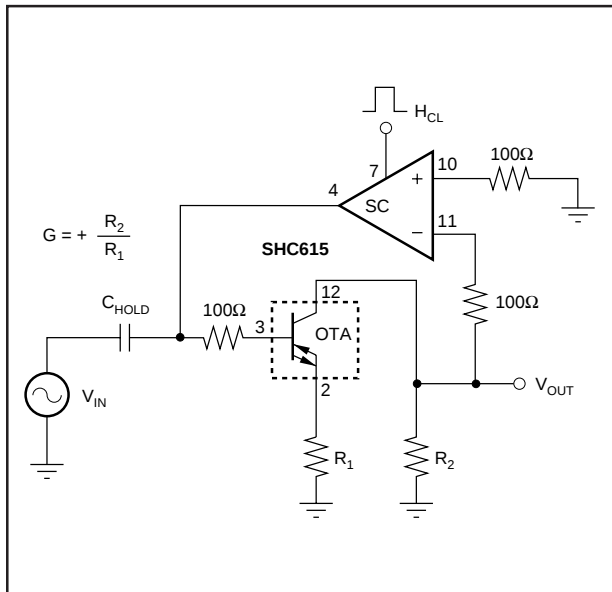


FIGURE 7. Complete DC Restoration System.

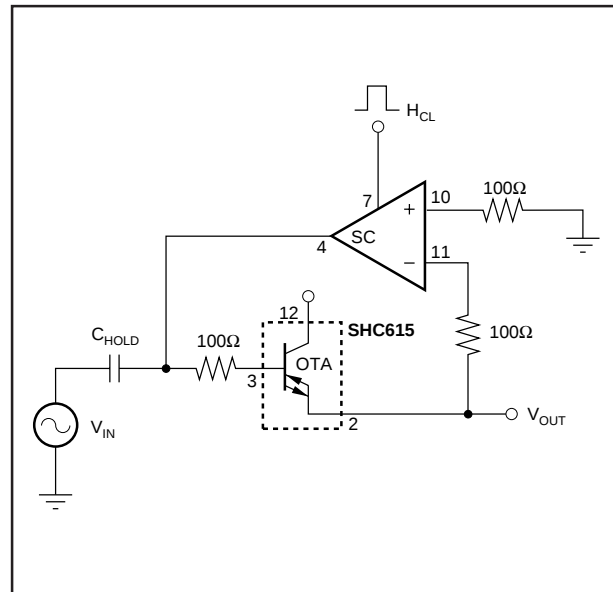


FIGURE 8. DC Restoration of a Buffer Amplifier.

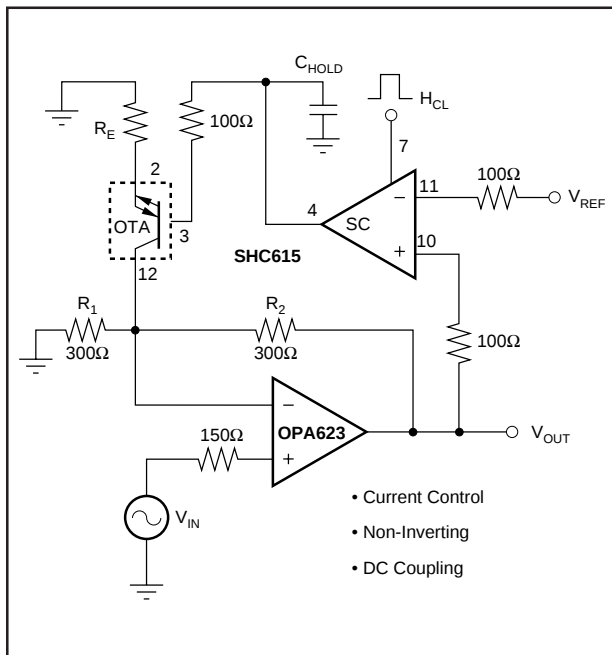


FIGURE 9. Clamped Video/RF Amplifier.

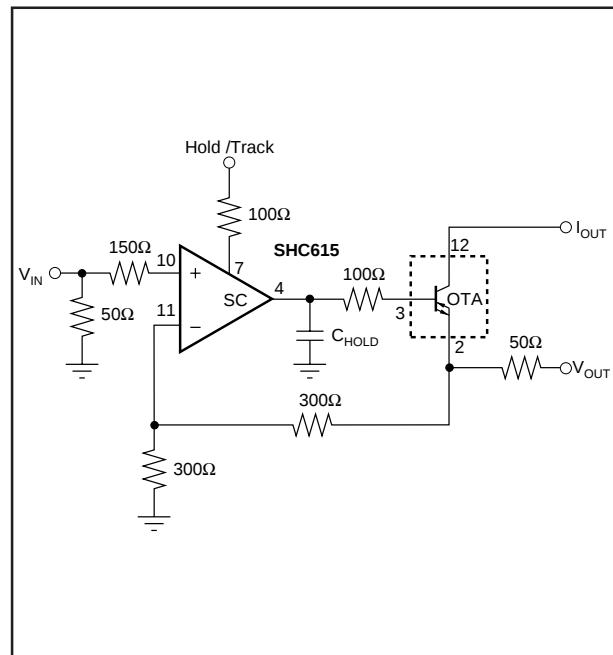


FIGURE 10. Sample/Hold Amplifier.

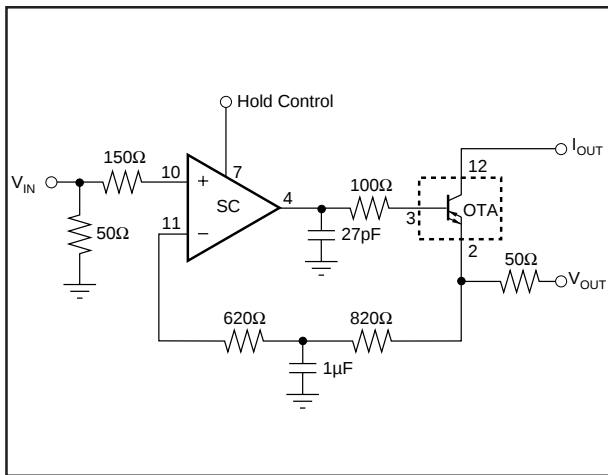


FIGURE 11. Integrator for ns-Pulses.

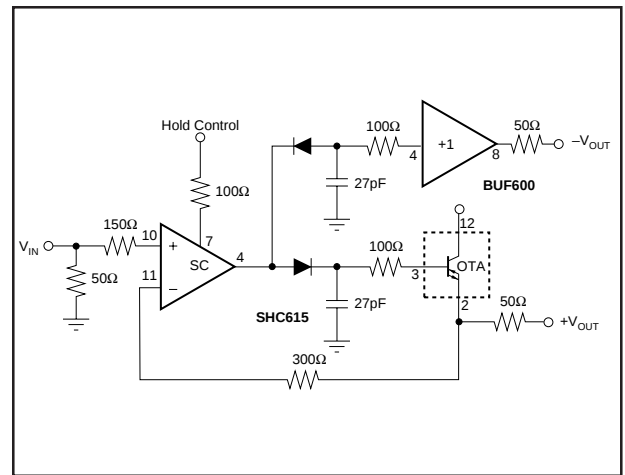


FIGURE 12. Fast Pulse Peak Detector.

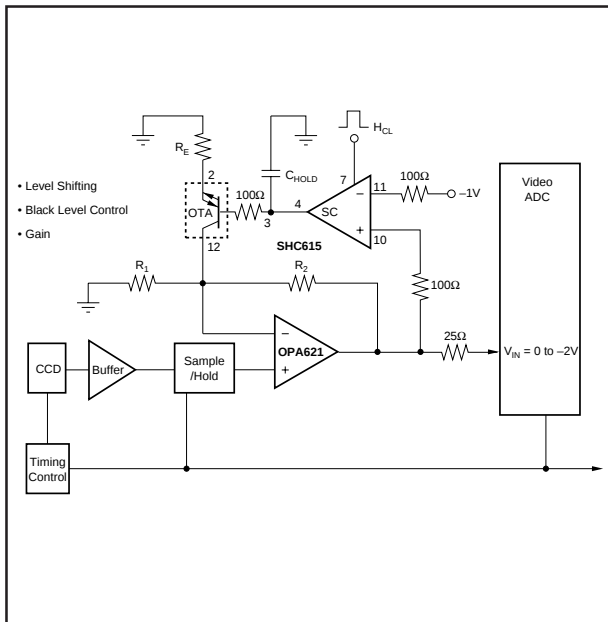


FIGURE 13. CCD Analog Front-End.

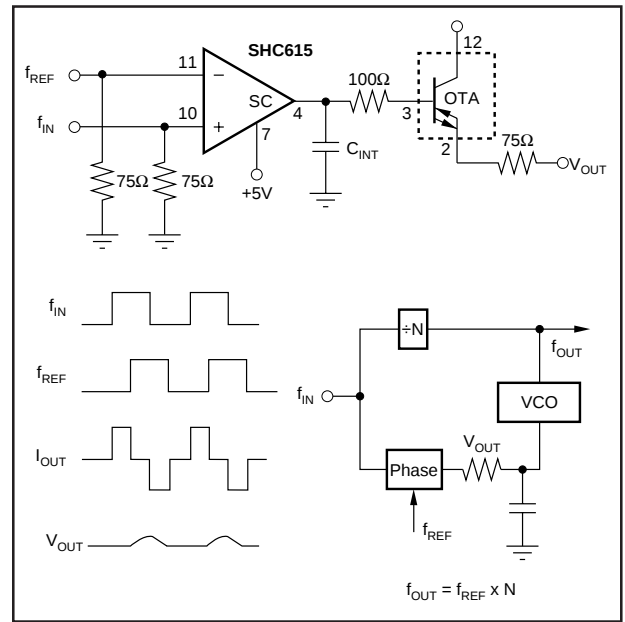


FIGURE 14. Phase Detector For Fast PLL-Systems.

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